

SN54S133, SN74S133 13-INPUT POSITIVE-NAND GATES

SDLS202 – DECEMBER 1983 – REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages, and Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

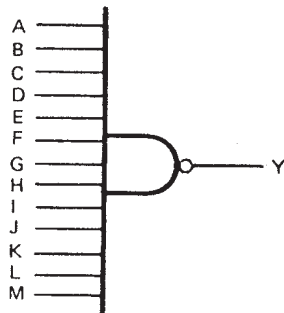
These devices contain a single 13-input NAND gate.

The SN54133 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74133 is characterized for operation from 0°C to 70°C .

FUNCTION TABLE

INPUTS A THRU M	OUTPUT Y
All inputs H	L
One or more inputs L	H

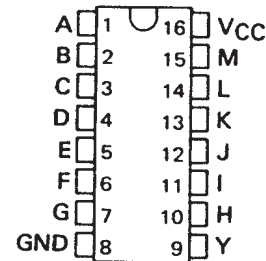
logic diagram



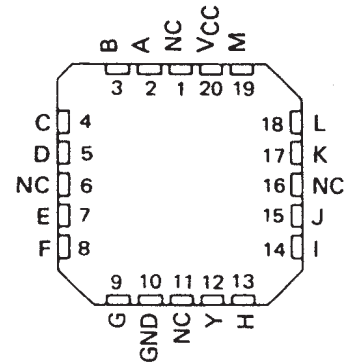
positive logic

$$Y = \overline{A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H \cdot I \cdot J \cdot K \cdot L \cdot M} \text{ or } Y = \overline{A + B + C + D + E + F + G + H + I + J + K + L + M}$$

SN54S133 . . . J OR W PACKAGE
SN74S133 . . . D OR N PACKAGE
(TOP VIEW)

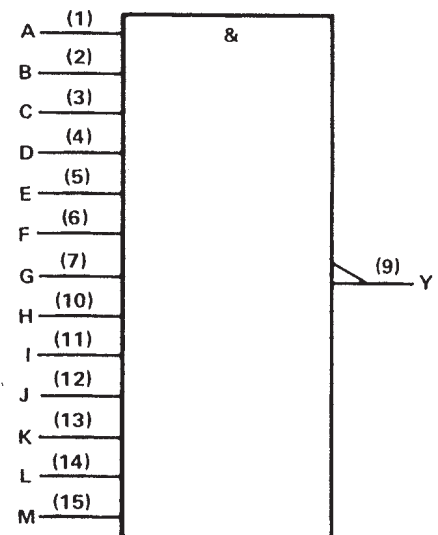


SN54S133 . . . FK PACKAGE
(TOP VIEW)



NC - No internal connection

logic symbol†



†This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

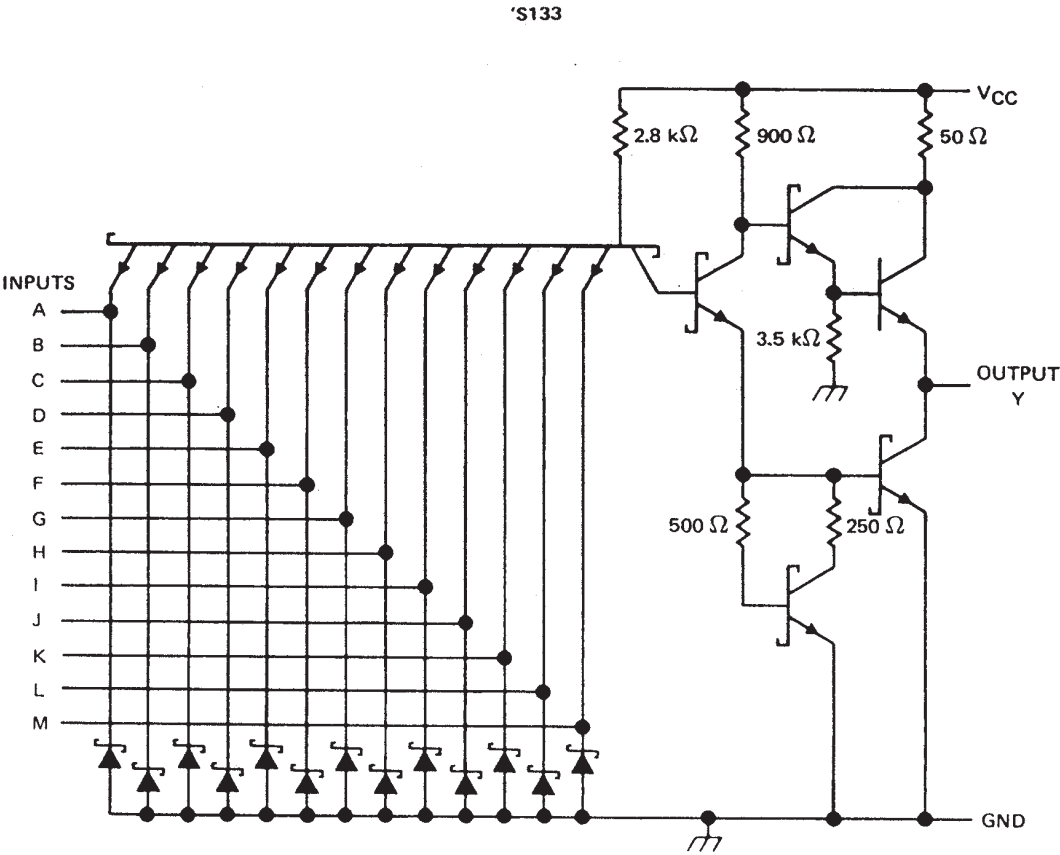
 **TEXAS
INSTRUMENTS**

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SN54S133, SN74S133
13-INPUT POSITIVE-NAND GATES

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Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage	5.5 V
Operating free-air temperature range: SN54'	– 55° C to 125° C
SN74'	0° C to 70° C
Storage temperature range	– 65° C to 150° C

NOTE 1: Voltage values are with respect to network ground terminal.



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recommended operating conditions

	SN54S133			SN74S133			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage			0.8			0.8	V
I _{OH} High-level output current			– 1			– 1	mA
I _{OL} Low-level output current			20			20	mA
T _A Operating free-air temperature	– 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54S133			SN74S133			UNIT
		MIN	TYP ‡	MAX	MIN	TYP ‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = –18 mA			–1.2			–1.2	V
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = –1 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 20 mA			0.5			0.5	V
I _I	V _{CC} = MAX, V _I = 5.5 V			1			1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			50			50	μA
I _{IL}	V _{CC} = MAX, V _I = 0.5 V			–2			–2	mA
I _{OS} §	V _{CC} = MAX	–40		–100	–40		–100	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V		3	5		3	5	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		5.5	10		5.5	10	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 280 Ω, C _L = 15 pF		4	6	ns
t _{PHL}					4.5	7	ns
t _{PLH}			R _L = 280 Ω, C _L = 50 pF		5.5		ns
t _{PHL}					6.5		ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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